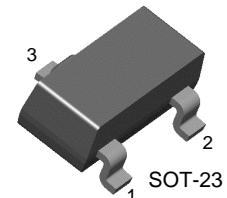


Low Noise Transistor



1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage : KST5088 : KST5089	35 30	V
V_{CEO}	Collector-Emitter Voltage : KST5088 : KST5089	30 25	V
V_{EBO}	Emitter-Base Voltage	4.5	V
I_C	Collector Current	50	mA
P_C	Collector Power Dissipation	350	mW
T_{STG}	Storage Temperature	150	°C

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

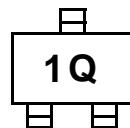
Symbol	Parameter	Test Condition	Min.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage : KST5088 : KST5089	$I_C=100\mu\text{A}, I_E=0$	35 30		V
BV_{CEO}	Collector-Emitter Breakdown Voltage : KST5088 : KST5089	$I_C=1\text{mA}, I_B=0$	30 25		V
I_{CBO}	Collector Cut-off Current : KST5088 : KST5089	$V_{CB}=20\text{V}, I_E=0$ $V_{CB}=15\text{V}, I_E=0$	50 50		nA nA
I_{EBO}	Emitter Cut-off Current	$V_{EB}=3\text{V}, I_C=0$	50		nA
h_{FE}	DC Current Gain : KST5088 : KST5089 : KST5088 : KST5089 : KST5088 : KST5089	$V_{CE}=5\text{V}, I_C=100\mu\text{A}$ $V_{CE}=5\text{V}, I_C=1\text{mA}$ $V_{CE}=5\text{V}, I_C=10\text{mA}$	300 400 350 450 300 400	900 1,200	
$V_{CE(\text{sat})}$	Collector-Emitter Saturation Voltage	$I_C=10\text{mA}, I_B=1\text{mA}$		0.5	V
$V_{BE(\text{sat})}$	Base-Emitter Saturation Voltage	$I_C=10\text{mA}, I_B=1\text{mA}$		0.8	V
f_T	Current Gain-Bandwidth Product	$V_{CE}=5\text{V}, I_C=500\mu\text{A}, f=20\text{MHz}$	50		MHz
C_{ob}	Output Capacitance	$V_{CB}=5\text{V}, I_E=0, f=100\text{KHz}$		4	pF
NF	Noise Figure : KST5088 : KST5089	$I_C=100\mu\text{A}, V_{CE}=5\text{V}$ $R_S=10\text{K}\Omega, f=10\text{Hz} \text{ to } 15.7\text{KHz}$		3 2	dB dB

KST5088/5089

Marking Code

Type	KST5088	KST5089
Mark	1Q	1R

Marking



Typical Characteristics

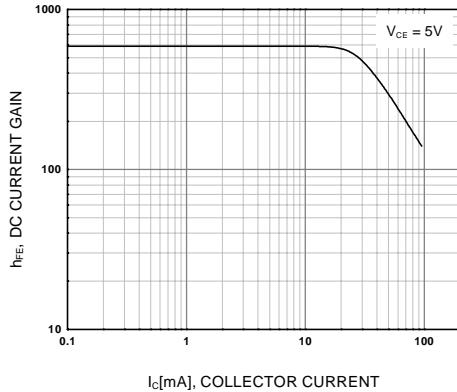


Figure 1. DC current Gain

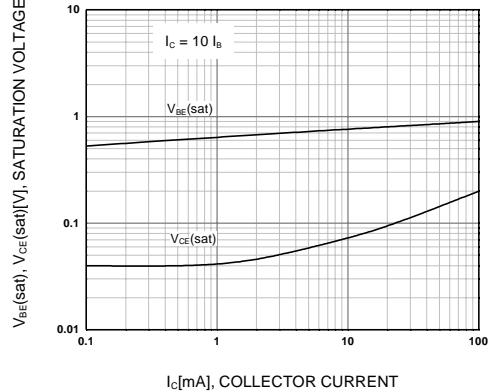


Figure 2. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

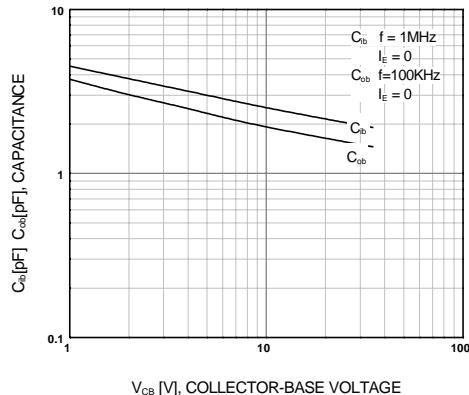


Figure 3. Output Capacitance
Collector-Base Capacitance

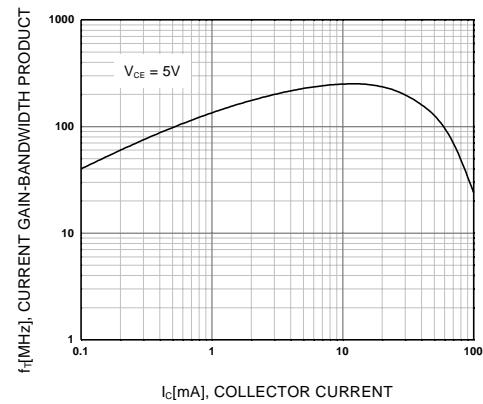
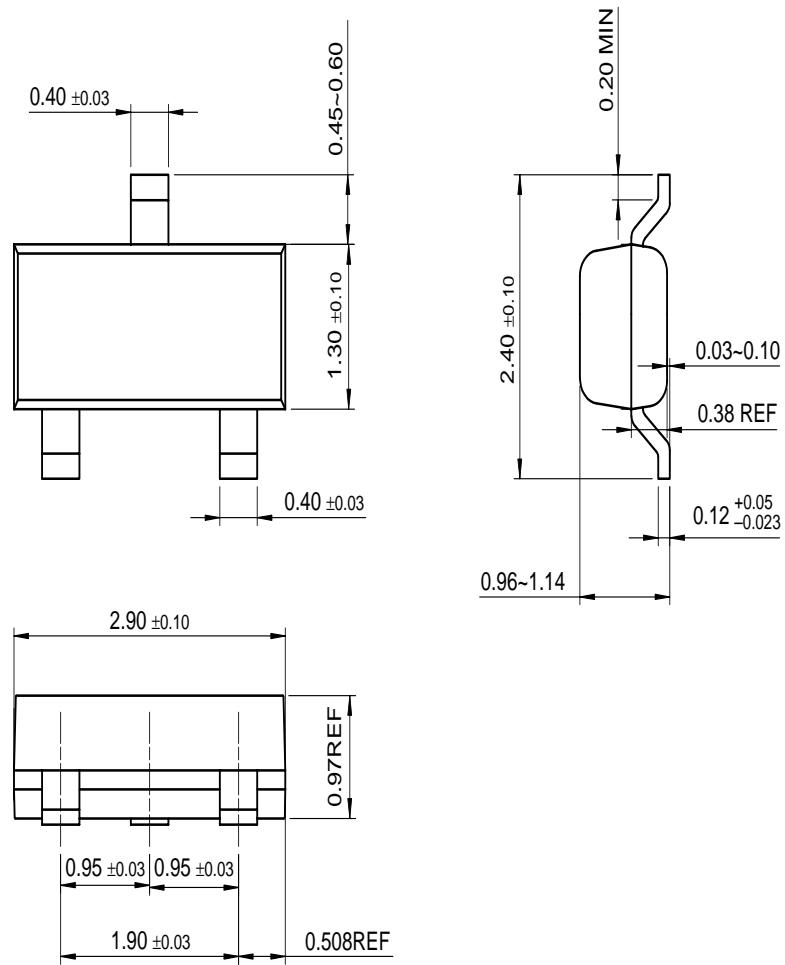


Figure 4. Current Gain Bandwidth Product

Package Dimensions

SOT-23



Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C™	OCX™	RapidConfigure™	UHC™
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The Power Franchise™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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